## NSN 5961-01-036-5813



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-036-5813 **Inclosure Material:** Metal **Overall Length:** Between 1.062 inches and 1.330 inches **Function For Which Designed:** Switching **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-61 **Mounting Method:** Threaded stud **Features Provided:** Burn in and hermetically sealed case **Overall Width Across Flats:** Between 0.667 inches and 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 150.0 collector to base voltage/static/emitter open and 90.0 collector to emitter voltage/static/base open and 8.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 5.00 amperes source cutoff current and 30.00 amperes source cutoff current **Power Rating Per Characteristic:** 4.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Collector is isolated from case; junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life:

Demilitarization:

**Unit Of Measure:** 

No

N/a

## **NSN 5961-01-036-5813** Transistor - Page 2 of 2



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